

# UNISONIC TECHNOLOGIES CO., LTD

## UTT100N06 Preliminary Power MOSFET

# N-CHANNEL ENHANCEMENT MODE POWER MOSFET

### ■ DESCRIPTION

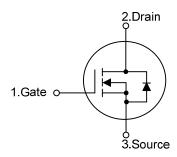
The UTC **UTT100N06** is an N-channel enhancement mode Power FET using UTC's advanced technology to provide customers with a minimum on-state resistance and superior switching performance.

It also can withstand high energy pulse in the avalanche and commutation mode.

#### ■ FEATURES

- \* Fast switching speed
- \* 100A, 60V,  $R_{DS(ON)}$ = 7m $\Omega$  @  $V_{GS}$ =10V
- \* Work below 175°C
- \* 100% avalanche tested
- \* Improved dv/dt capability

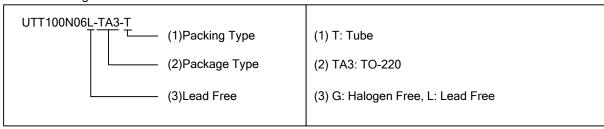
#### ■ SYMBOL

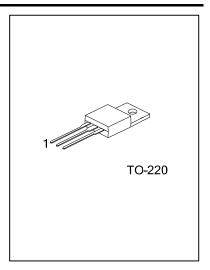


#### ORDERING INFORMATION

Ordering Number		Dooleage	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTT100N06L-TA3-T	UTT100N06G-TA3-T	TO-220	G	D	S	Tube	

Note: Pin Assignment: G: Gate D: Drain S: Source





## ■ ABSOLUTE MAXIMUM RATINGS (T<sub>J</sub>=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		$V_{DSS}$	60	V	
Gate-Source Voltage		$V_{GSS}$	±20	V	
Drain Current	Continuous	I <sub>D</sub>	100	Α	
	Pulsed	I <sub>DM</sub>	400	Α	
Avalanche Energy	Single Pulsed	E <sub>AS</sub>	875	mJ	
Peak Diode Recovery dv/dt		dv/dt	6	V/ns	
Power Dissipation		$P_{D}$	100	W	
Junction Temperature		$T_J$	+150	°C	
Storage Temperature		T <sub>STG</sub>	-55~+150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	$\theta_{JA}$	62.5	°C/W	
Junction to Case	$\theta_{JC}$	1.5	°C/W	

#### ■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub>=25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS			•		_		
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	I <sub>D</sub> =250μA, V <sub>GS</sub> =0V	60			V
Drain-Source Leakage Current		I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V			10	μΑ
Gate- Source Leakage Current	Forward		$V_{GS}$ =+20V, $V_{DS}$ =0V			+100	nA
	Reverse	I <sub>GSS</sub>	V <sub>GS</sub> =-20V, V <sub>DS</sub> =0V			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1		3	V
Static Drain-Source On-State Resistance		D	V <sub>GS</sub> =10V, I <sub>D</sub> =50A		7		mΩ
		$R_{DS(ON)}$	V <sub>GS</sub> =4.5V, I <sub>D</sub> =40A		10		mΩ
DYNAMIC PARAMETERS							
nput Capacitance		C <sub>ISS</sub>			12900		pF
Output Capacitance		Coss	$V_{GS}$ =0V, $V_{DS}$ =25V, f=1.0MHz		1060		pF
Reverse Transfer Capacitance	Reverse Transfer Capacitance				700		pF
SWITCHING PARAMETERS							
Total Gate Charge		$Q_G$			500		nC
Gate to Source Charge		$Q_GS$	$V_{GS}$ =10V, $V_{DS}$ =30V, $I_{D}$ =100A		50		nC
Gate to Drain Charge		$Q_GD$			33		nC
Turn-ON Delay Time		t <sub>D(ON)</sub>			90		ns
Rise Time		$t_R$	$V_{DD}$ =30V, VGS=10V, $I_D = 100A$ ,		130	200	ns
Turn-OFF Delay Time		t <sub>D(OFF)</sub>	$R_G=0.4\Omega$		768		ns
Fall-Time		t <sub>F</sub>			280	420	ns
Transconductance		<b>g</b> fs	V <sub>DS</sub> =15V, I <sub>D</sub> =30A	30			S
SOURCE- DRAIN DIODE RATIF	NGS AND (	CHARACTER	ISTICS				
Maximum Body-Diode Continuous Current		Is		100			Α
Maximum Body-Diode Pulsed Current		I <sub>SM</sub>		400			Α
Drain-Source Diode Forward Voltage		$V_{SD}$	I <sub>S</sub> =100A, V <sub>GS</sub> =0V		1.0	1.5	V
Resistance of Gate		$R_G$		0.65	1.3	2	Ω

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